		Sheet 1 of 1	
FORM PTO-1449 FEB 0 2 2001 6	Atty. Docket No.: M923.12-0001	Application No.: 10/662,748	
LIST OF PATENTS AND PUBLICATIONS FOR	First Named Inventor: Zahilya Austin		
APPLICANTS INFORMATION DISCLOSURE STATEMENT	Filing Date: September 15, 2003	Group Art: 2817	

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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449						Atty. Docket No.: M923.12-0001	Application No.: 10/662,748			
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